RS101 thru RS107 SERIES

SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIER





Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At TA=25°C unless otherwise noted)

RATINGS		RS101	RS102	RS103	RS104	RS105	RS106	RS107	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at @ T _A =50°C	I _o	1.0							A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	30							A
Operating Temperature Range	Тј	-55 to +125							°C
Storage Temperature Range	T _{STG}	-55 to +150						°C	

ELECTRICAL CHARACTERISTICS (At TA=25°C unless otherwise noted)

CHARACTERISTICS			RS101	RS102	RS103	RS104	RS105	RS106	RS107	UNITS
Maximum Forward Voltage Drop per element of 1.0A DC $$\rm V_{\rm F}$$		1.0							V	
Maximum Reverse Current at Rated DC Blocking Voltage per element	@ T _A =25°C	. I _R				10				μA
	@ T _A =100°C		1							mA

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RATING AND CHARACTERISTICS CURVES RS101 THRU RS107





Fig.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



Fig.4 - TYPICAL REVERSE CHARACTERISTICS

